# NUP4060AXV6

# **ESD Protection Diode Array,** 4-Line

This 4-line surge protection array is designed for application requiring transient voltage protection capability. It is intended for use in over-transient voltage and ESD sensitive equipment such as cell phones, portables, computers, printers and other applications. This device features a common cathode design which protects four independent lines in a single SOT-563 package.

#### Features

- Protects up to 4 Lines in a Single SOT-563 Package
- ESD Rating: IEC61000-4-2: Level 4
  - Contact (8 kV), Air (15 kV)
- V<sub>CC</sub> Pin = 16 V Protection
  - D1, D2, and D3 Pins = 6.8 V Protection
- Low Capacitance (< 7 pF @ 3 V) for D<sub>1</sub>, D<sub>2</sub>, and D<sub>3</sub>
- This is a Pb–Free Device

#### Applications

- Hand Held Portable Applications
- USB Interface
- Notebooks, Desktops, Servers
- SIM Card Protection

#### MAXIMUM RATINGS (T<sub>J</sub> = 25°C, unless otherwise specified)

| Symbol            | Rating   | Value         | Unit |
|-------------------|--|---------------|------|
| P <sub>PK</sub> 1 | Peak Power Dissipation V <sub>CC</sub> Diode<br>8x20 µsec double exponential waveform, | 200           | W    |
|                   | (Note 1) D <sub>1</sub> , D <sub>2</sub> , and D <sub>3</sub>                          | 20            | W    |
| TJ                | Operating Junction Temperature Range   | -40 to 125    | °C   |
| T <sub>STG</sub>  | Storage Temperature Range  | –55 to 150    | °C   |
| TL                | Lead Solder Temperature – Maximum<br>(10 seconds)                                      | 260           | °C   |
| ESD               | IEC 61000-4-2 Air<br>IEC 61000-4-2 Contact   | 15000<br>8000 | V    |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

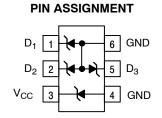
1. Nonrepetitive current pulse per Figure 1.

ON

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# SOT-563 4-LINE SURGE PROTECTION



#### MARKING DIAGRAM





MT = Specific Device Code

M = Date Code

SOT-563

CASE 463A STYLE 6

= Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

| Device         | Package              | Shipping <sup>†</sup> |
|----------------|----------------------|-----------------------|
| NUP4060AXV6T1G | SOT-563<br>(Pb-Free) | 4000/Tape & Reel      |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

# NUP4060AXV6

### ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = 25°C, unless otherwise specified)

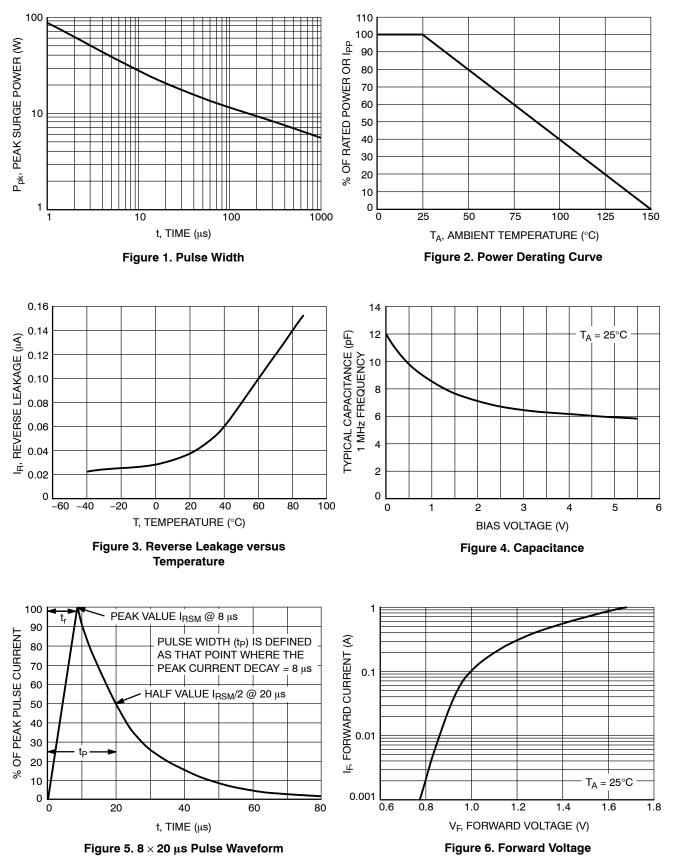
| Parameter   | Conditions                           | Symbol           | Min  | Тур  | Max  | Unit |
|---|--------------------------------------|------------------|------|------|------|------|
| Reverse Working Voltage ( $D_1$ , $D_2$ , and $D_3$ )               | (Note 2)                             | V <sub>RWM</sub> | -    | -    | 5.0  | V    |
| Breakdown Voltage ( $D_1$ , $D_2$ , and $D_3$ )                     | I <sub>T</sub> = 1 mA, (Note 3)      | V <sub>BR</sub>  | 6.2  | 6.8  | 7.2  | V    |
| Breakdown Voltage (V <sub>CC</sub> )                                | I <sub>T</sub> = 5 mA, (Note 3)      | V <sub>BR2</sub> | 15.3 | 16   | 17.1 | V    |
| Reverse Leakage Current $(D_1, D_2, and D_3)$                       | V <sub>RWM</sub> = 3 V               | Ι <sub>R</sub>   | -    | 0.01 | 0.5  | μA   |
| Reverse Leakage Current (V <sub>CC</sub> )                          | V <sub>BR</sub> = 11 V               | Ι <sub>R</sub>   | -    | -    | 0.05 | μA   |
| Capacitance (D <sub>1</sub> , D <sub>2</sub> , and D <sub>3</sub> ) | $V_R$ = 3 V, f = 1 MHz (Line to GND) | CJ               | -    | 7    | 10   | pF   |

Surge protection devices are normally selected according to the working peak reverse voltage (V<sub>RWM</sub>), which should be equal or greater than the DC or continuous peak operating voltage level.
V<sub>BR</sub> is measured at pulse test current I<sub>T</sub>.

## NUP4060AXV6



(Diode D<sub>1</sub>, D<sub>2</sub>, and D<sub>3</sub> only)



6Х

(

MILLIMETERS

NDM.

0.55

0.22

0.13

1.60

1.20

0.50 BSC

0.20

1.60

MAX.

0.60

0.27

0.18

1.70

1.30

0.30

1.70

SIDE VIEW

MIN.

0.50

0.17

0.08

1.50

1.10

0.10

1.50

DIM

Α

b

С

D E

e L

 $\mathsf{H}_\mathsf{E}$ 



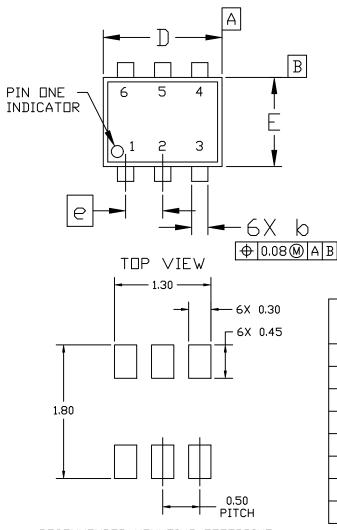


SOT-563, 6 LEAD CASE 463A ISSUE H

DATE 26 JAN 2021

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- NDTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 1. DIMENSIONING AND TOLERANCING PER A 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS DF BASE MATERIAL.



RECOMMENDED MOUNTING FOOTPRINT\* \* For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

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| STYLE 1:  | STYLE 2:  | STYLE 3:         |
|---|---|------------------|
| PIN 1. EMITTER 1  | PIN 1. EMITTER 1  | PIN 1. CATHIDE 1 |
| 2. BASE 1   | 2. EMITTER 2  | 2. CATHIDE 1     |
| 3. COLLECTOR 2  | 3. BASE 2   | 3. ANUDE/ANUDE 2 |
| 4. EMITTER 2  | 4. COLLECTOR 2  | 4. CATHIDE 2     |
| 5. BASE 2   | 5. BASE 1   | 5. CATHIDE 2     |
| 6. COLLECTOR 1  | 6. COLLECTOR 1  | 6. ANUDE/ANUDE 1 |
| STYLE 4:  | STYLE 5:  | STYLE 6:         |
| PIN 1. COLLECTOR  | PIN 1. CATHEDE  | PIN 1. CATHODE   |
| 2. COLLECTOR  | 2. CATHEDE  | 2. ANODE         |
| 3. BASE   | 3. ANEDE  | 3. CATHODE       |
| 4. EMITTER  | 4. ANEDE  | 4. CATHODE       |
| 5. COLLECTOR  | 5. CATHEDE  | 5. CATHODE       |
| 6. COLLECTOR  | 6. CATHEDE  | 6. CATHODE       |
| STYLE 7:  | STYLE 8:  | STYLE 9:         |
| PIN 1. CATHODE  | PIN 1. DRAIN  | PIN 1. SDURCE 1  |
| 2. ANODE  | 2. DRAIN  | 2. GATE 1        |
| 3. CATHODE  | 3. GATE   | 3. DRAIN 2       |
| 4. CATHODE  | 4. SDURCE   | 4. SDURCE 2      |
| 5. ANODE  | 5. DRAIN  | 5. GATE 2        |
| 6. CATHODE  | 6. DRAIN  | 6. DRAIN 1       |
| STYLE 10:<br>PIN 1. CATHODE 1<br>2. N/C<br>3. CATHODE 2<br>4. ANODE 2<br>5. N/C<br>6. ANODE 1 | STYLE 11:<br>PIN 1. EMITTER 2<br>2. BASE 2<br>3. COLLECTOR 1<br>4. EMITTER 1<br>5. BASE 1<br>6. COLLECTOR 2 |                  |

6. COLLECTOR 2

DATE 26 JAN 2021

#### GENERIC **MARKING DIAGRAM\***



XX = Specific Device Code

M = Month Code

. = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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|                  |                 |   |             |  |

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